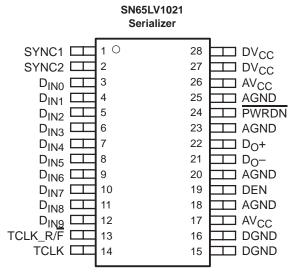
- 100-Mbps to 400-Mbps Serial LVDS Data Payload Bandwidth at 10-MHz to 40-MHz System Clock
- Pin-Compatible Superset of NSM DS92LV1021/DS92LV1212
- Chipset (Serializer/Deserializer) Power Consumption <350 mW (Typ) at 40 MHz
- Synchronization Mode for Faster Lock

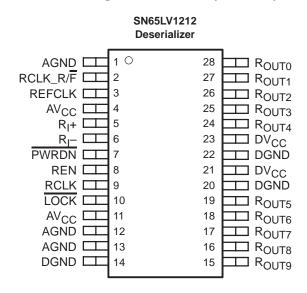


Lock Indicator

No External Components Required for PLL

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- Low-Cost 28-Pin SSOP Package
- Industrial Temperature Qualified, T_∆ = −40°C to 85°C
- Programmable Edge Trigger on Clock (Rising or Falling Edge)
- Flow-Through Pinout for Easy PCB Layout



description

The SN65LV1021 serializer and SN65LV1212 deserializer comprise a 10-bit serdes chipset designed to transmit and receive serial data over LVDS differential backplanes at equivalent parallel word rates from 10 MHz to 40 MHz. Including overhead, this translates into a serial data rate between 120-Mbps and 480-Mbps payload-encoded throughput.

Upon power up, the chipset link can be initialized via a synchronization mode with internally generated SYNC patterns, or the deserializer can be allowed to synchronize to random data. By using the synchronization mode, the deserializer establishes lock within specified, shorter time parameters.

The device can be entered into a power-down state when no data transfer is required. Alternatively, a mode is available to place the output pins in the high-impedance state without losing PLL lock.

The SN65LV1021 and SN65LV1212 are characterized for operation over ambient air temperature of –40°C to 85°C.

ORDERING INFORMATION			
DEVICE PART NUMBER			
Serializer	SN65LV1021DB		
Deserializer	SN65LV1212DB		



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

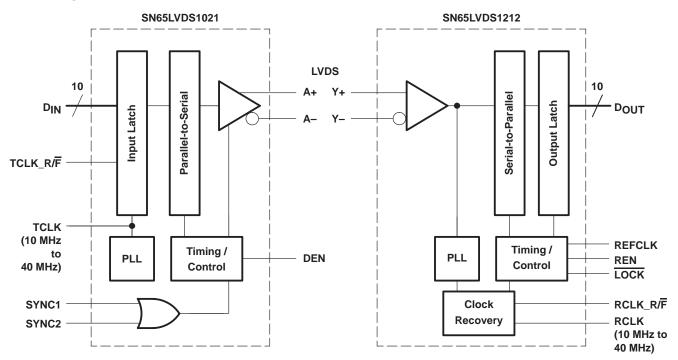
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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block diagrams



functional description

The SN65LV1021 and SN65LV1212 are a 10-bit serializer/deserializer chipset designed to transmit data over differential backplanes or unshielded twisted pair (UTP) at clock speeds from 10 MHz to 40 MHz. The chipset has five states of operation: initialization mode, synchronization mode, data transmission mode, power-down mode, and high-impedance mode. The following sections describe each state of operation.

initialization mode

Initialization of both devices must occur before data transmission can commence. Initialization refers to synchronization of the serializer and deserializer PLLs to local clocks.

When V_{CC} is applied to the serializer and/or deserializer, the respective outputs enter the high-impedance state, while on-chip power-on circuitry disables internal circuitry. When V_{CC} reaches 2.45 V, the PLL in each device begins locking to a local clock. For the serializer, the local clock is the transmit clock (TCLK) provided by an external source. For the deserializer, a local clock must be applied to the REFCLK pin. The serializer outputs remain in the high-impedance state, while the PLL locks to the TCLK.



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functional description (continued)

synchronization mode

The deserializer PLL must synchronize to the serializer in order to receive valid data. Synchronization can be accomplished in one of two ways:

Rapid Synchronization: The serializer has the capability to send specific SYNC patterns consisting of six
ones and six zeros switching at the input clock rate. The transmission of SYNC patterns enables the
deserializer to lock to the serializer signal within a deterministic time frame. This transmission of SYNC
patterns is selected via the SYNC1 and SYNC2 inputs on the serializer. Upon receiving valid a SYNC1 or
SYNC2 pulse (wider than 6 clock cycles), 1026 cycles of SYNC pattern are sent.

When the deserializer detects edge transitions at the LVDS input, it attempts to lock to the embedded clock information. The deserializer LOCK output remains high while its PLL locks to the incoming data or SYNC patterns present on the serial input. When the deserializer locks to the LVDS data, the LOCK output goes low. When LOCK is low, the deserializer outputs represent incoming LVDS data. One approach is to tie the deserializer LOCK output directly to SYNC1 or SYNC2.

• Random-Lock Synchronization: The deserializer can attain lock to a data stream without requiring the serializer to send special SYNC patterns. This allows the SN65LV1212 to operate in open-loop applications. Equally important is the deserializer's ability to support hot insertion into a running backplane. In the open-loop or hot-insertion case, it is assumed the data stream is essentially random. Therefore, because lock time varies due to data stream characteristics, the exact lock time cannot be predicted. The primary constraint on the random lock time is the initial phase relation between the incoming data and the REFCLK when the deserializer powers up.

The data contained in the data stream can also affect lock time. If a specific pattern is repetitive, the deserializer could enter false lock—falsely recognizing the data pattern as the start/stop bits. This is referred to as repetitive multitransition (RMT); see Figure 1 for RMT examples. RMT occurs when more than one low-high transition takes place per clock cycle over multiple cycles. In the worst case, the deserializer could become locked to the data pattern rather than the clock. Circuitry within the deserializer can detect that the possibility of false lock exists. Upon detection, the circuitry prevents the LOCK output from becoming active until the potential false lock pattern changes. Notice that the RMT pattern only affects the deserializer lock time, and once the deserializer is in lock, the RMT pattern does not affect the deserializer state as long as the same data boundary happens each cycle. The deserializer does not go into lock unitil it finds a unique four consecutive cycles of data boundary (stop/start bits) at the same position.

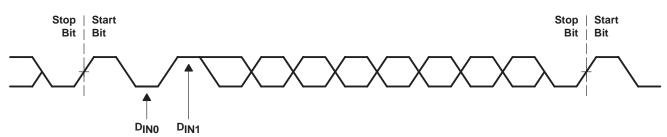
The deserializer stays in lock until it cannot detect the same data boundary (stop/start bits) for four consecutive cycles. Then the desiralizer goes out of lock and hunts for the new data boundary (stop/start bits). In the event of loss of synchronization, the LOCK pin output goes high and the outputs (including RCLK) enter a high-impedance state. The user's system should monitor the LOCK pin in order to detect a loss of synchronization. Upon detection of loss of lock, sending sync patterns for resynchronization is desirable if reestablishing lock within a specific time is critical. However, the deserializer can lock to random data as previously noted.



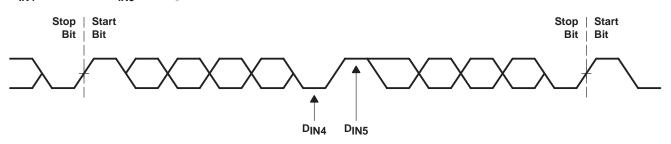
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synchronization mode (continued)

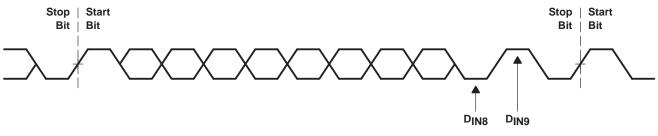
DIN0 Held Low and DIN1 Held High



DIN4 Held Low and DIN5 Held High



DIN8 Held Low and DIN9 Held High





data transmission mode

After initialization and synchronization, the serializer accepts parallel data from inputs $D_{IN0} - D_{IN9}$. The serializer uses the TCLK input to latch the incoming data. The TCLK_R/ \overline{F} pin selects which edge the serializer uses to strobe incoming data. If either of the SYNC inputs is high for 6 TCLK cycles, the data at $D_{IN0} - D_{IN9}$ is ignored regardless of the clock edge selected and 1026 cycles of SYNC pattern are sent.

After determining which clock edge to use, a start and stop bit, appended internally, frames the data bits in the register. The start bit is always high and the stop bit is always low. The start and stop bits function as the embedded clock bits in the serial stream.

The serializer transmits serialized data and appended clock bits (10+2 bits) from the serial data output (DO±) at 12 times the TCLK frequency. For example, if TCLK is 10 MHz, the serial rate is $10 \times 12 = 120$ Mbps. Because only 10 bits are input data, the useful data rate is 10 times the TCLK frequency. For instance, if TCLK = 12 MHz, the useful data rate is $10 \times 12 = 120$ Mbps. The data source, which provides TCLK, must be in the range of 10 MHz to 40 MHz.



functional description (continued)

The serializer outputs (DO±) can drive point-to-point connections or limited multipoint or multidrop backplanes. The outputs transmit data when the enable pin (DEN) is high, PWRDN is high, and SYNC1 and SYNC2 are low. When DEN is driven low, the serializer output pins enter the high-impedance state.

Once the deserializer has synchronized to the serializer, the \overline{LOCK} pin transitions low. The deserializer locks to the embedded clock and uses it to recover the serialized data. R_{OUTx} data is valid when \overline{LOCK} is low, otherwise $R_{OUT0}-R_{OUT9}$ is invalid. The $R_{OUT0}-R_{OUT9}$ data is strobed out by RCLK. The specific RCLK edge polarity to be used is selected by the RCLK_R/F input. The $R_{OUT0}-R_{OUT9}$, \overline{LOCK} and RCLK outputs can drive a maximum of three CMOS input gates (15-pF load, total for all three) with a 40-MHz clock.

power down

When no data transfer is required, the power-down mode can be used. The serializer and deserializer use the power-down mode, a low-power sleep mode, to reduce power consumption. The deserializer enters power down when you drive PWRDN and REN low. The serializer enters power down when the PWRDN is driven low. In power down, the PLL stops and the outputs enter a high-impedance state, which disables load current and reduces supply current to the milliampere range. To exit power down, you must drive the PWRDN pin high.

Before valid data exchanges between the serializer and deserializer can resume, you must reinitialize and resynchronize the devices to each other. Initialization of the serializer takes 1026 TCLK cycles. The deserializer initializes and drives LOCK high until lock to the LVDS clock occurs.

high-impedance mode

The serializer enters the high-impedance mode when the DEN pin is driven low. This puts both driver output pins (DO+ and DO–) into a high-impedance state. When you drive DEN high, the serializer returns to its previous state, as long as all other control pins remain static (SYNC1, SYNC2, PWRDN, TCLK_R/F). When the REN pin is driven low, the deserializer enters high-impedance mode. Consequently, the receiver output pins ($R_{OUT0}-R_{OUT9}$) and RCLK are placed into the high-impedance state. The LOCK output remains active, reflecting the state of the PLL.

INPU	тѕ	OUTPUTS		
PWRDN	REN	ROUT[0:9]	LOCK	RCLK
Н	Н	Z	Н	Z
Н	Н	Active	L	Active
L	Х	Z	Z	Z
Н		Z	Active	Z

Deserializer	Truth	Table
DOCOLIGIEO		IGNIO

NOTES: 1. LOCK output reflects the state of the deserializer with regard to the selected data stream.

- RCLK active indicates the RCLK is running if the deserializer is locked. The timing of RCLK with respect to ROUT is determined by RCLK_R/F.
- 3. ROUT and RCLK are 3-stated when $\overline{\text{LOCK}}$ is asserted high.



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Terminal Functions

serializer

PIN	NAME	DESCRIPTION
1, 2	SYNC1, SYNC2	LVTTL logic inputs SYNC1 and SYNC2 are ORed together. When at least one of the two pins is asserted high for 6 cycles of TCLK, the serializer initiates transmission of a minimum 1026 SYNC patterns. If after completion of transmission of 1026 patterns SYNC continues to be asserted, then the transmission continues until SYNC is driven low and if the time SYNC holds > 6 cycles, another 1026 SYNC pattern transmission initiates.
3-12	DIN0-DIN9	Parallel LVTTL data inputs
13	TCLK_R/F	LVTTL logic input. Low selects a TCLK falling-edge data strobe; high selects a TCLK rising-edge data strobe.
14	TCLK	LVTTL-level reference clock input. The SN65LV1021 accepts a 10-MHz to 40-MHz clock. TCLK strobes parallel data into the input latch and provides a reference frequency to the PLL.
15, 16	DGND	Digital circuit ground
18, 20, 23, 25	AGND	Analog circuit ground (PLL and analog circuits)
17, 26	AVCC	Analog circuit power supply (PLL and analog circuits)
19	DEN	LVTTL logic input. Low puts the LVDS serial output into the high-impedance state. High enables serial data output.
21	D _O -	Inverting LVDS differential output
22	D _O +	Noninverting LVDS differential output
27, 28	DVCC	Digital circuit power supply
24	PWRDN	LVTTL logic input. Asserting this pin low turns off the PLL and places the outputs into the high-impedance state, putting the device into a low-power mode.

deserializer

PIN	NAME	DESCRIPTION
3	REFCLK	LVTTL logic input. Use this pin to supply a REFCLK signal for the internal PLL frequency.
15–19, 24–28	ROUT0-ROUT9	Parallel LVTTL data outputs
2	RCLK_R/F	LVTTL logic input. Low selects an RCLK falling-edge data strobe; high selects an RCLK rising-edge data strobe.
9	RCLK	LVTTL-level output recovered clock. Use RCLK to strobe ROUTx.
14, 20, 22	DGND	Digital circuit ground
1, 12, 13	AGND	Analog circuit ground (PLL and analog circuits)
4, 11	AVCC	Analog circuit power supply (PLL and analog circuits)
8	REN	LVTTL logic input. Low places ROUT0-ROUT9, LOCK, and RCLK in the high-impedance state.
5	R _l +	Serial data input. Noninverting LVDS differential input
6	RI–	Serial data input. Inverting LVDS differential input
10	LOCK	LVTTL-level output. LOCK goes low when the deserializer PLL locks onto the embedded clock edge.
21, 23	DVCC	Digital circuit power supply
7	PWRDN	LVTTL logic input. Asserting this pin low turns off the PLL and places outputs into a high-impedance state, putting the device into a low-power mode.



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absolute maximum ratings (unless otherwise noted)[†]

V _{CC} to GND LVTTL input voltage LVTTL output voltage LVDS receiver input voltage LVDS driver output voltage LVDS output short circuit duration Electrostatic discharge: HBM MM	$\begin{array}{cccc} & -0.3 \ V \ to \ (V_{CC} + 0.3 \ V) \\ & & -0.3 \ V \ to \ (V_{CC} + 0.3 \ V) \\ & & & -0.3 \ V \ to \ 3.9 \ V \\ & & & & -0.3 \ V \ to \ 3.9 \ V \\ & & & & & -0.3 \ V \ to \ 3.9 \ V \\ & & & & & & & \\ & & & & & \\ & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & \\ & & & & & & $
Junction temperature	150°C
Storage temperature Lead temperature (soldering, 4 seconds)	
Maximum package power dissipation, T _A = 25°C Package derating	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC} ‡	3	3.3	3.6	V
Receiver input voltage range	0		2.4	V
Receiver input common mode range, V _{CM}	$\frac{V_{ID}}{2}$	2	$2.4 - \left(\frac{V_{\text{ID}}}{2}\right)$	V
Supply noise voltage			100	mV _{P-P}
Operating free-air temperature, T _A	-40	25	85	°C

[‡] By design, DVCC and AVCC are separated internally and does not matter what the difference is for |DVCC-AVCC|, as long as both are within 3 V to 3.6 V.



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electrical characteristics over recommended operating supply and temperature ranges (unless otherwise noted)

	PARAMETER	TEST CONDITION	TEST CONDITIONS		TYP	MAX	UNIT
SERIAL	IZER LVCMOS/LVTTL DC SPECIFICATION	IS (see Note 4)					
VIH	High-level input voltage			2		VCC	V
VIL	Low-level input voltage			GND		0.8	V
VCL	Input clamp voltage	I _{CL} = -18 mA				-1.5	V
I _{IN}	Input current (see Note 5)	V _{IN} = 0 V or 3.6 V		-200	±100	200	μΑ
DESERI	IALIZER LVCMOS/LVTTL DC SPECIFICATI	ONS (see Note 6)					
VIH	High-level input voltage			2		Vcc	V
VIL	Low-level input voltage			GND		0.8	V
VCL	Input clamp voltage	I _{CL} = -18 mA			-0.62	-1.5	V
I _{IN}	Input current	V _{IN} = 0 V or 3.6 V		-200		200	μΑ
Vон	High-level output voltage	$I_{OH} = -5 \text{ mA}$		2.2	3	Vcc	V
VOL	Low-level output voltage	I _{OL} = 5 mA		GND	0.25	0.5	V
los	Output short-circuit current	V _{OUT} = 0 V		-15	-47	-85	mA
loz	High-impedance output current	PWRDN or REN = 0.8 V, VOUT =	-10	±1	10	μΑ	
SERIAL	IZER LVDS DC SPECIFICATIONS (apply to	pins DO+ and DO–)					
Vod	Output differential voltage (DO+)-(DO-)		350	400		mV	
∆Vod	Output differential voltage unbalance	$R_L = 27 \Omega$, See Figure 18			35	mV	
Vos	Offset voltage		1.1	1.2	1.3	V	
∆Vos	Offset voltage unbalance					35	mV
los	Output short circuit current	D0 = 0 V, D _{INx} = high, PWRDN a	nd DEN = 2.4 V		-10	-90	mA
Ioz	High-impedance output current	PWRDN or DEN = 0.8 V, DO = 0	V or V _{CC}	-10	±1	10	μΑ
IOX	Power-off output current	$V_{CC} = 0 V, DO = 0 V \text{ or } V_{CC}$		-20	±1	20	μΑ
DESERI	IALIZER LVDS DC SPECIFICATIONS (appl	y to pins RI+ and RI–)					
VTH	Differential threshold high voltage	V _{CM} = 1.1 V				50	mV
VTL	Differential threshold low voltage			-50			mV
	logut ourroat	$V_{IN} = 2.4 \text{ V}, \text{ V}_{CC} = 3.6 \text{ V} \text{ or } 0 \text{ V}$		-10	±1	15	
IN	Input current	$V_{IN} = 0 V, V_{CC} = 3.6 V \text{ or } 0 V$		-10	±0.05	10	μA
SERIAL	IZER SUPPLY CURRENT (applies to pins	DVCC and AVCC)					
	Serializer supply current worst cose	RI - 27 O See Figure 2	f = 40 MHz		40	50	mA
ICCD	Serializer supply current, worst case	$R_L = 27 \Omega$, See Figure 2	f = 10 MHz		20	25	IIIA
ICCXD	Serializer supply current, power down	PWRDN = 0.8 V			200	500	μΑ
DESERI	IALIZER SUPPLY CURRENT (applies to pi	ns DVCC and AVCC)					
10.00	Departializar augulu aurrant, warst saas		f = 40 MHz		63	75	m^
ICCR	Deserializer supply current, worst case	C _L = 15 pF, See Figure 3	f = 10 MHz		15	35	mA
ICCXR	Deserializer supply current, power down	PWRDN = 0.8 V, REN = 0.8 V			0.36	1	mA

NOTES: 4. Apply to DINO-DIN9, TCLK, PWRDN, TCLK_R/F, SYNC1, SYNC2, DEN

5. High I_{IN} values are due to pull-up and pull-down resistors on the inputs.

6. Apply to input pins PWRDN, RCLK_R/F, REN, REFCLK; apply to output pins R_{OUTx}, RCLK, LOCK



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serializer timing requirements for TCLK over recommended operating supply and temperature ranges (unless otherwise specified)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{TCP}	Transmit clock period		25	Т	100	ns
^t TCIH	Transmit clock high time		0.4T	0.5T	0.6T	ns
^t TCIL	Transmit clock low time		0.4T	0.5T	0.6T	ns
^t t(CLK)	TCLK input transition time	See Figure 6		3	6	ns
^t JIT	TCLK input jitter				150	ps (RMS)

serializer switching characteristics over recommended operating supply and temperature ranges (unless otherwise specified)

	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
tTLH(L)	LVDS low-to-high transition time	$R_L = 27 \Omega$, $C_L = 10 pF$ to GND,		0.2	1	ns
tTHL(L)	LVDS high-to-low transition time	See Figure 4		0.25	1	ns
t _{su(DI)}	DIN0-DIN9 setup to TCLK	$R_L = 27 \Omega$, $C_L = 10 pF$ to GND,	1	0		ns
^t h(D)	DIN0-DIN9 hold from TCLK	See Figure 7	6.5	4.5		ns
^t d(HZ)	$\text{DO}\pm$ high-to-high impedance state delay			2.5	5	ns
^t d(LZ)	$\text{DO}\pm$ low-to-high impedance state delay	$R_L = 27 \Omega$, $C_L = 10 pF$ to GND,		2.5	5	ns
^t d(ZH)	$\text{DO}\pm$ high-impedance state-to-high delay	See Figure 8		2.5	10	ns
td(ZL)	$\text{DO}\pm$ high-impedance state-to-low delay			2.7	10	ns
tw(SP)	SYNC pulse duration	$R_{I} = 27 \Omega$, See Figure 9 and	6×tTCP			ns
^t PLD	Serializer PLL lock time	Figure 10	1026×tTCP			ns
^t d(S)	Serializer delay	R _L = 27 Ω, See Figure 11		t _T	<u>CP</u> + 3	ns
t(BIT)	Bus LVDS bit width	$R_L = 27 \Omega$, $C_L = 10 \text{ pF to GND}$		t _{CLK} /12		ns



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deserializer timing requirements for REFCLK over recommended operating supply and temperature ranges (unless otherwise specified)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
^t RFCP	REFCLK period		25	Т	100	ns
^t RFDC	REFCLK duty cycle		40%	50%	60%	
^t t(RF)	REFCLK transition time			3	6	ns

deserializer switching characteristics over recommended operating supply and temperature ranges (unless otherwise specified)

	PARAMETER	TEST CONDITIONS	PIN/FREQ	MIN	ТҮР	МАХ	UNIT	
^t RCP	Receiver out clock period	^t (RCP) = ^t (TCP) See Figure 11	RCLK	25		100	ns	
^t TLH(C)	CMOS/TTL low-to-high transition time	С _L =15 рF,	R _{OUT0} - R _{OUT9} ,		0.7	2.5	ns	
^t THL(C)	CMOS/TTL high-to-low transition time	See Figure 5	LOCK, RCLK		1.1	2.5	ns	
4	Deserializer delay,	Room	10 MHz	2×t _{RCP} + 9		2.833×t _{RCP} + 14		
^t d(D)	See Figure 12	temperature, 3.3 V	40 MHz	2×t _{RCP} + 6		2.833×t _{RCP} + 10	ns	
^t su(ROS)	R _{OUT0} –R _{OUT9} setup data to RCLK		0.4×t _{RCP} 0.5×t _{RCP}				-	
^t (ROH)	R _{OUT0} –R _{OUT9} hold data to RCLK	See Figure 13	-0.4×tRCP	-0.5×tRCP		ns		
^t (RDC)	RCLK duty cycle	1		40%	50%	60%		
^t d(HZ)	High-to-high impedance state delay				6.7	8	ns	
^t d(LZ)	Low-to-high impedance state delay	Coo Figure 44	ROUT0-		4.6	8	ns	
^t d(ZH)	High-impedance state-to-high delay	See Figure 14			5.5	8	ns	
^t d(ZL)	High-impedance state-to-low delay				4.8	8	ns	
	Deserializer PLL lock time from		10 MHz			(1024+26)t _{RFCP}		
^t (DSR1)	PWRDN (with SYNCPAT)	See Figure 15,	40 MHz			(1024+26)tRFCP	μs	
+	Deserializer PLL lock time from	Figure 16, and	10 MHz			0.7	μο	
^t (DSR2)	SYNCPAT	Note 7	40 MHz			0.2		
^t d(ZHL)	High-impedance state-to-high delay (power up)		LOCK			3	ns	
^t (RNM)	Deserializer noise margin	See Figure 17	10 MHz		3680		ps	
		and Note 8	40 MHz		1100			

NOTES: 7. t_(DSR1) represents the time required for the deserializer to register that a lock has occurred upon power up or when leaving the power-down mode. t_(DSR2) represents the time required to register that a lock has occurred for the powered up and enabled deserializer when the input (RI±) conditions change from not receiving data to receiving synchronization patterns (SYNCPATs). In order to specify deserializer PLL performance t_{DSR1} and t_{DSR2} are specified with REFCLK active and stable and specific conditions of SYNCPATs.

8. tRNM represents the phase noise or jitter that the deserializer can withstand in the incoming data stream before bit errors occur.



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timing diagrams and test circuits

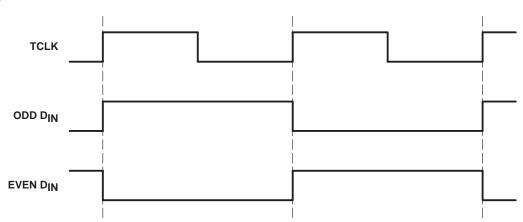
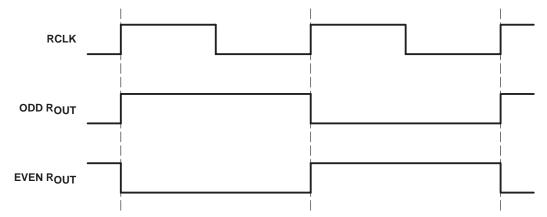
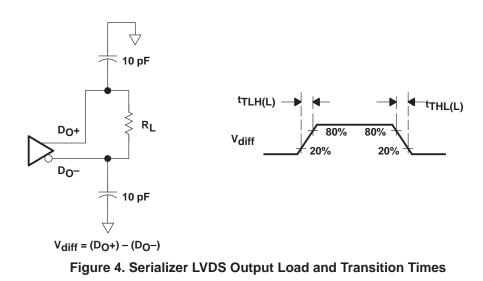


Figure 2. Worst-Case Serializer I_{CC} Test Pattern









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timing diagrams and test circuits (continued)

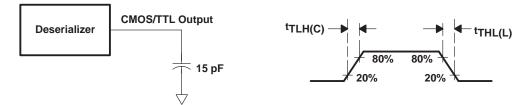


Figure 5. Deserializer CMOS/TTL Output Load and Transition Times

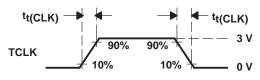


Figure 6. Serializer Input Clock Transition Time

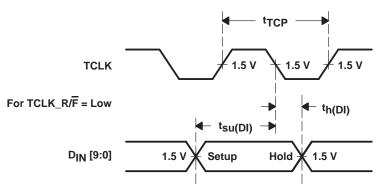


Figure 7. Serializer Setup/Hold Times

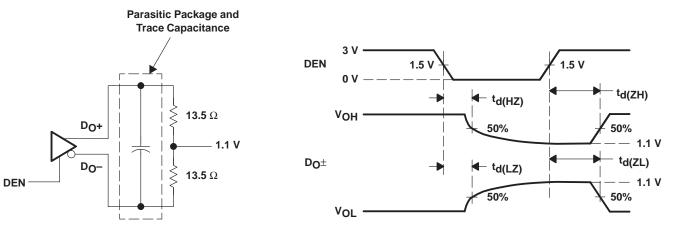
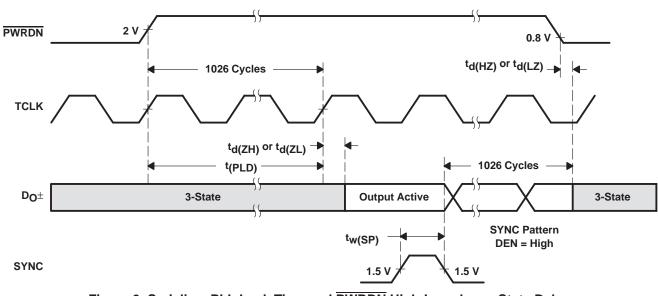


Figure 8. Serializer High-Impedance-State Test Circuit and Timing

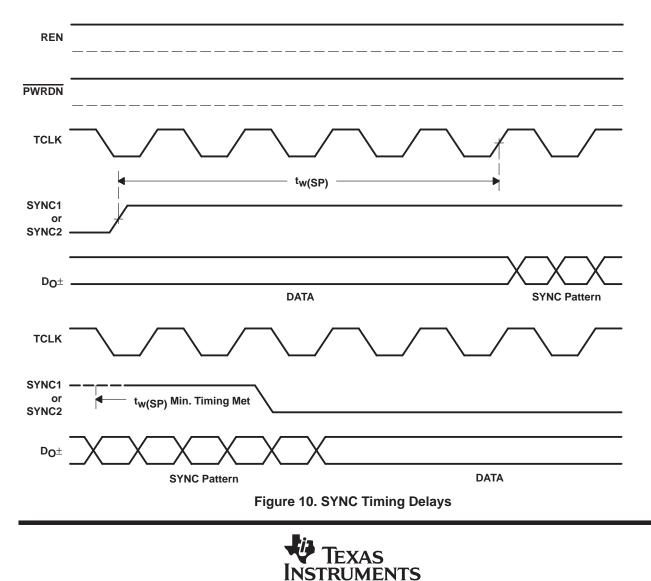


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timing diagrams and test circuits (continued)

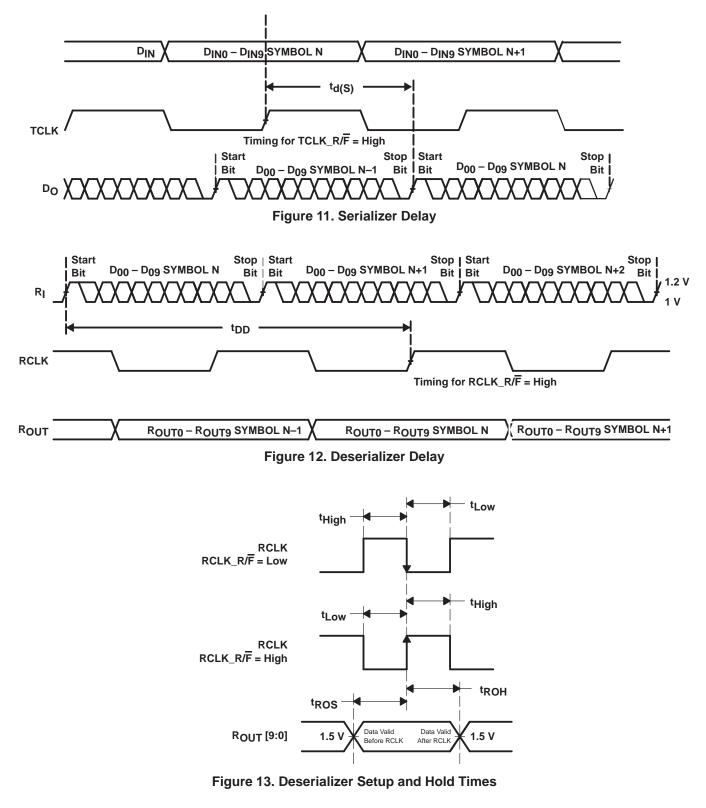




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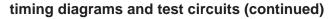
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timing diagrams and test circuits (continued)





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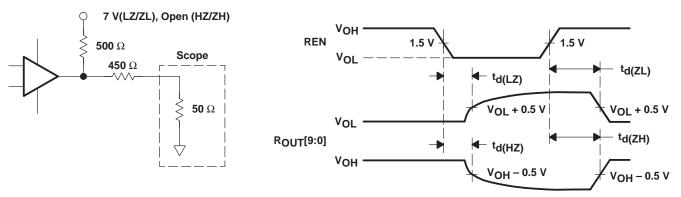


Figure 14. Deserializer High-Impedance-State Test Circuit and Timing

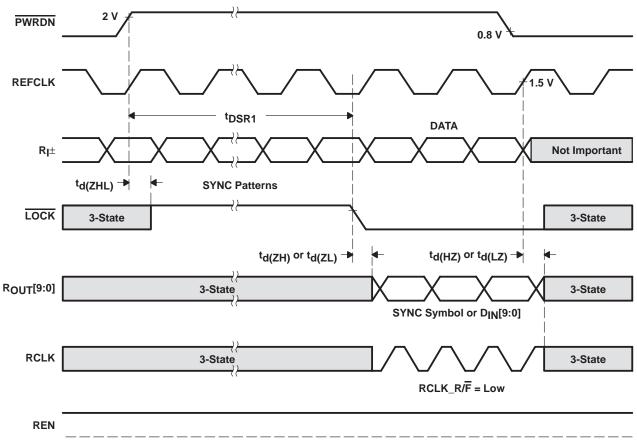


Figure 15. Receiver LVDS Input Skew Margin



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timing diagrams and test circuits (continued)

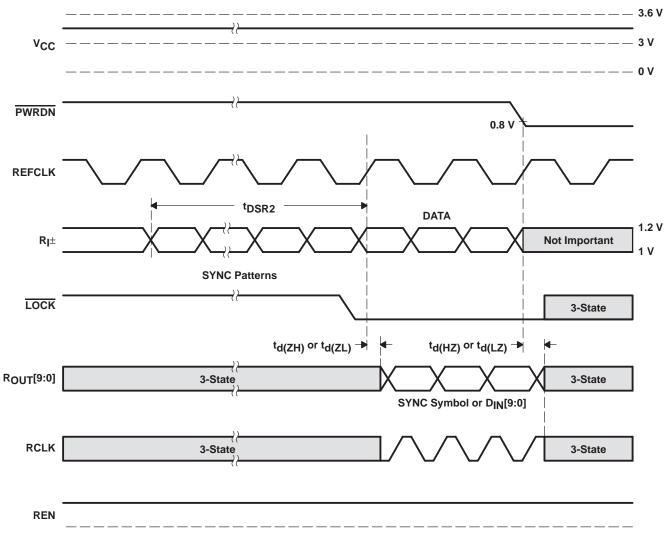
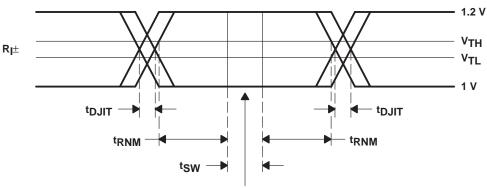


Figure 16. Deserilaizer PLL Lock Time From SyncPAT



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timing diagrams and test circuits (continued)



Ideal Sampling Position

t_{SW}: Setup and Hold Time (Internal Data Sampling Window) t_{DJIT}: Serializer Output Bit Position Jitter That Results From Jitter on TCLK t_{RNM}: Receiver Noise Margin Time



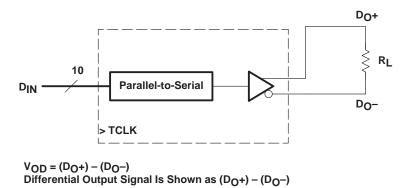


Figure 18. V_{OD} Diagram

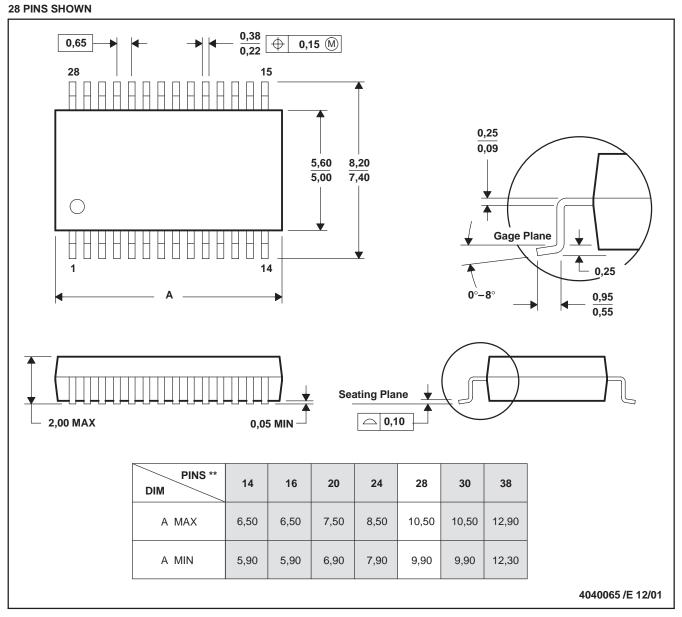


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MECHANICAL DATA

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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